imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





High Power Infrared Emitter

Product No: MTE8600N2

Peak Emission Wavelength: 860nm

The MTE8600N2 consists of a 860nm high output infrared die in a water-clear 5mm flat top plastic molded package. Custom package solutions and sorting are available.

FEATURES

- > High Output Power
- > Wide Beam Angle
- > High Reliability

- APPLICATIONS
 - > Optical Switches & Sensors
 - > Fiber Optical Communication



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Absolute Maximum Ratings (Ta=25°C)

	0 (/		
TEMS	SYMBOL	RATINGS	UNIT	lead-free
Forward Current (DC)	IF	100	mA	
Forward Current (Pulse)*1	IFP	1	A	
Reverse Voltage	VR	5	V	
Power Dissipation	PD	190	mW	
Operating Temperature Range	Topr	-20 ~ +80	°C	
Storage Temperature Range	Tstg	-30 ~ +100	°C	
Junction Temperature	Tj	100	°C	
Lead Soldering Temperature*2	Tls	260	℃	

*1: Tw=10µsec, T=10msec. *2: Time 5Sec max, Position: Up to 3mm from the body.

Electrical & Optical Characteristics (Ta = 25°C)

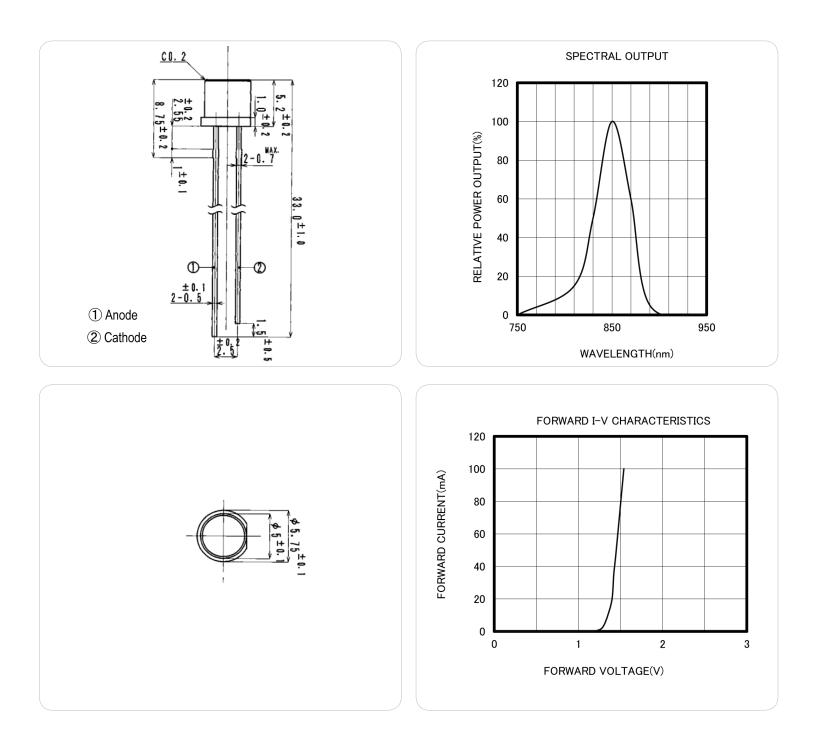
ITEMS	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNIT
Power Output	PO	IF=50mA		18.0		mW
Forward Voltage	VF	IF=50mA		1.45	1.9	V
Reverse Current	IR	VR=5V			100	μA
Peak Emission Wavelength	λρ	IF=50mA		850		nm
Spectral Line Half Width	Δλ	IF=50mA		30		nm
Half Intensity Beam Angle	θ	IF=50mA		±55		deg

2012-05-17



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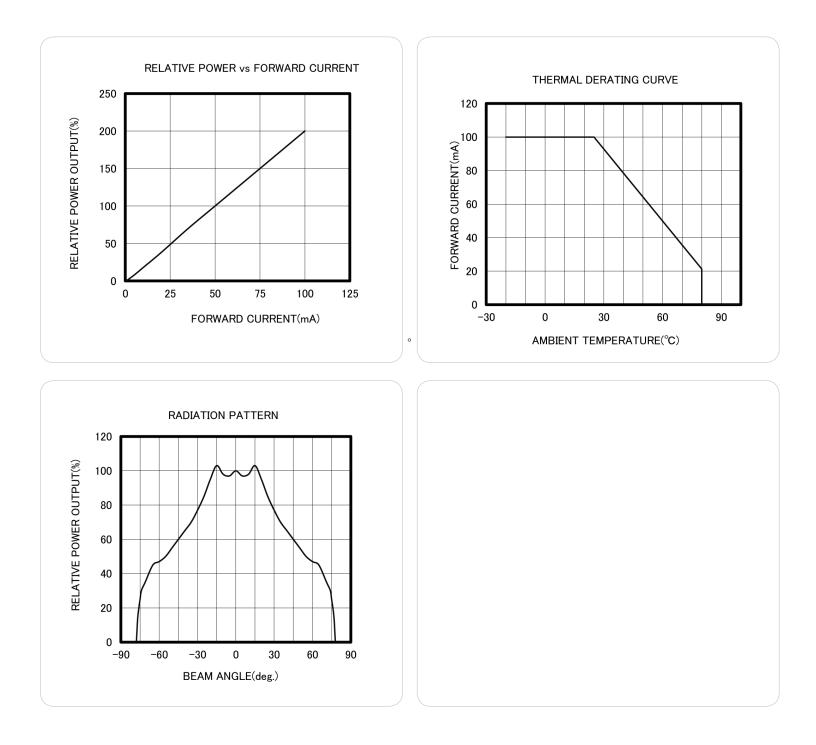
Unit: mm, Tolerance: ±0.2

Global Headquarters, 3 Northway Lane North, Latham, NY 12110, USA **www.marktechopto.com TOLL FREE:** 1-800-984-5337 • **PHONE:** 518-956-2980 • **FAX:** 518-785-4725 • **EMAIL:** info@marktechopto.com 2



High Power Infrared Emitter

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The information contained herein is subject to change without notice.

2012-05-17